NSN 5961-00-754-9560

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-754-9560 **Inclosure Material:** Glass and metal **Overall Length:** Between 0.220 inches and 0.335 inches Overall Diameter: Between 0.360 inches and 0.400 inches **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Germanium Voltage Rating In Volts Per Characteristic: 300.0 reverse voltage, peak **Current Rating Per Characteristic:** 0.175 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 90.0 degrees celsius ambient air **Test Data Document:** 81349-mil-e-1 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 81349-mil-e-1/895 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No